

472

C-MOS laser displacement sensor

CD33 series



Half-palm size. Ideal for built-in use with smaller machines.

- | Specular reflection types have been added to the line up
- | Control units for Mitsubishi Electric PLC are available

| | | | |
|-------------------------|---|---|---|
| Related products | Ultra-high accuracy CDX ● P.438 | Connecting to MELSEC-Q UQ1-02 ● P.520 | Compact type CD22 ● P.464 |
|-------------------------|---|---|---|

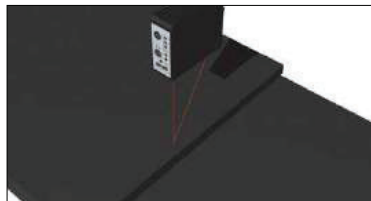
Substrate warpage measurement



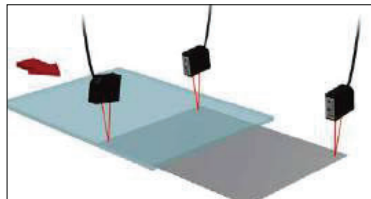
Height measurement of mounted parts



Seam detection on rubber sheeting



Mask height control and glass substrate thickness measurement (Specular reflection type)



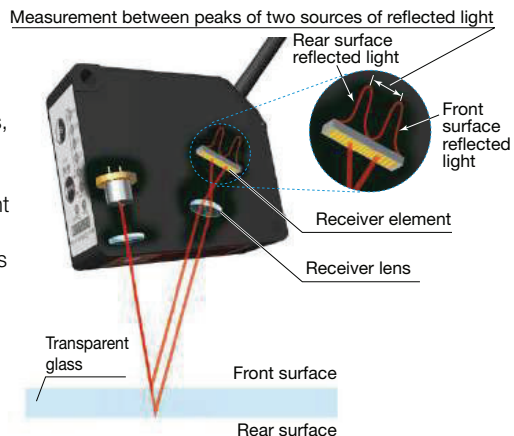
Specular reflection types

for measurements of specular and transparent objects.

Specular reflection types have been added to the line up to enable the measurement of transparent objects such as glass workpiece, as well as specular objects such as wafers, etc. This means that transparent and specular objects that were difficult to measure using diffuse-reflective types can now be measured with stability.

Thickness measurements also possible

When using a specular reflection type to measure transparent objects, not only surface displacement, but also thickness can be measured. As shown below, when the laser light is emitted at an angle, light reflected from both the front and rear surfaces of the glass are received by receiver element. Thickness measurements are possible by measuring between the peaks of these reflected light forms.

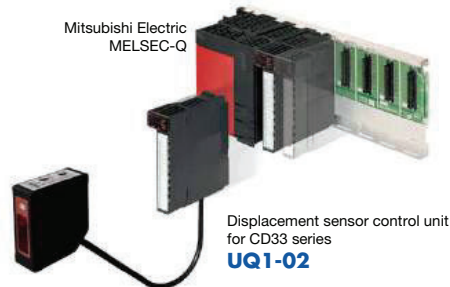


Direct connection to Mitsubishi Electric PLCs

The UQ1-02 displacement sensor control unit that can be connected to the Mitsubishi Electric MELSEC-Q series!

In addition to the fact that absolutely no communications settings are necessary, by using the specialized UQ1 Navigator software it is possible for any one to perform set up easily in a short period of time.

*Can be used with the RS-422 type of the CD33 series
UQ1-02 description ● P.520



Photoelectric Sensors

Specialized Photoelectric Sensors

Laser Displacement Sensors

C-MOS Built-in Amplifiers

CDX

CDA

LS

CD22

CD33









CD4

CD5

UQ1-01

UQ1-02

Selection table

| Type | Measurement range | Repeat accuracy | Analog output/serial interface | Control output | Model (Models in parentheses are connector types) | |
|---|--|-------------------|--------------------------------|--|---|--|
| | | | | | NPN type | PNP type |
|  Diffuse-reflective type (Laser Class 2) |  30 ± 4 mm | 2 μm (4 μm*) | 4 to 20 mA | 2ch | CD33-30NA (CD33-30CNA) | CD33-30PA (CD33-30CPA) |
| | | | 0 to 10 V | | CD33-30NV (CD33-30CNV) | CD33-30PV (CD33-30CPV) |
| | | | RS-422 | 1ch | CD33-30N-422 (CD33-30CN-422) | CD33-30P-422 (CD33-30CP-422) |
| |  50 ± 10 mm | 5 μm (8 μm*) | 4 to 20 mA | 2ch | CD33-50NA (CD33-50CNA) | CD33-50PA (CD33-50CPA) |
| | | | 0 to 10 V | | CD33-50NV (CD33-50CNV) | CD33-50PV (CD33-50CPV) |
| | | | RS-422 | 1ch | CD33-50N-422 (CD33-50CN-422) | CD33-50P-422 (CD33-50CP-422) |
| |  85 ± 20 mm | 10 μm (15 μm*) | 4 to 20 mA | 2ch | CD33-85NA (CD33-85CNA) | CD33-85PA (CD33-85CPA) |
| | | | 0 to 10 V | | CD33-85NV (CD33-85CNV) | CD33-85PV (CD33-85CPV) |
| | | | RS-422 | 1ch | CD33-85N-422 (CD33-85CN-422) | CD33-85P-422 (CD33-85CP-422) |
| |  120 ± 60 mm | 30 μm (45 μm*) | 4 to 20 mA | 2ch | CD33-120NA (CD33-120CNA) | CD33-120PA (CD33-120CPA) |
| | | | 0 to 10 V | | CD33-120NV (CD33-120CNV) | CD33-120PV (CD33-120CPV) |
| | | | RS-422 | 1ch | CD33-120N-422 (CD33-120CN-422) | CD33-120P-422 (CD33-120CP-422) |
|  250 ± 150 mm | 75 μm (100 μm*) | 4 to 20 mA | 2ch | CD33-250NA (CD33-250CNA) | CD33-250PA (CD33-250CPA) | |
| | | 0 to 10 V | | CD33-250NV (CD33-250CNV) | CD33-250PV (CD33-250CPV) | |
| | | RS-422 | 1ch | CD33-250N-422 (CD33-250CN-422) | CD33-250P-422 (CD33-250CP-422) | |
|  Specular reflection type (Laser Class 1) |  26.3 ± 2 mm | 1 μm | RS-422 | 1ch | CD33-L30N-422 (CD33-L30CN-422) | CD33-L30P-422 (CD33-L30CP-422) |
| |  47.3 ± 5 mm | 2.5 μm | | | CD33-L50N-422 (CD33-L50CN-422) | CD33-L50P-422 (CD33-L50CP-422) |
| |  82.9 ± 10 mm | 5 μm | | | CD33-L85N-422 (CD33-L85CN-422) | CD33-L85P-422 (CD33-L85CP-422) |

*The repeat accuracy when response time is set to FAST is shown in parentheses.
 ● For the connector type, please purchase an optional **DOL-1208-G05MF** connector cable.
 ● When using a UQ1-02 control unit, select the RS-422 communication type.

Options/Accessories

Connector cable

DOL-1208-G05MF
 M12, 8-pin connector cable
 Cable length: 5 m



Displacement sensor control unit



UQ1-02
 For connecting to the Mitsubishi Electric MELSEC-Q series
 * Can be used with the RS-422 type of the CD33 series



Photoelectric Sensors

Specialized Photoelectric Sensors

Laser Displacement Sensors

C-MOS Built-in Amplifiers

CDX

CDA

LS

CD22

CD33

CD4

CD5

UQ1-01

UQ1-02

C-MOS laser displacement sensor CD33 series

Original built-in technology

Lightweight with a built-in amplifier!

An amplifier and all control functions are integrated into the sensor head. You don't have to worry about space for installing to control panels.

It also features a light weight of approx. 65 g, enabling it to be installed to movable parts such as chip mounters or robot arms.



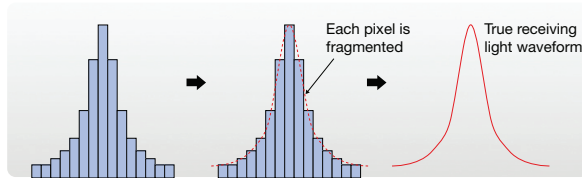
Uses sub-pixel processing and automatic sensitivity switching function

Pursuit of the limits in terms of accuracy and measurement stability!

Sub-pixel processing that recognizes true waveforms

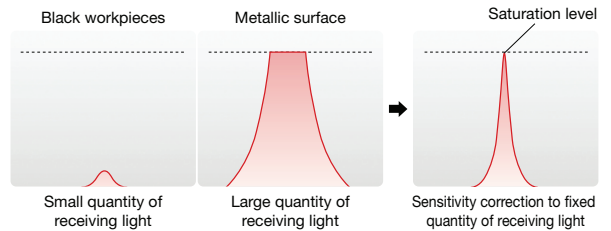
Sub-pixel processing is employed that performs recognition by fragmenting each C-MOS element pixel. By accurately detecting the true receiving light waveform, it is possible to correctly measure the distance to a workpiece. Repeat accuracy is also $2 \mu\text{m}^*$ and support is provided for high-accuracy displacement measurement.

*Values with CD33-30N□



High-accuracy sensitivity switching function effective against influence caused by workpiece material and color

The opening degree of the shutter is switched automatically in accordance with the reflection rate of the workpiece. By controlling the receiving light quantity and constantly correcting to the optimal sensitivity, we have succeeded in keeping errors caused by color and materials to an absolute minimum.

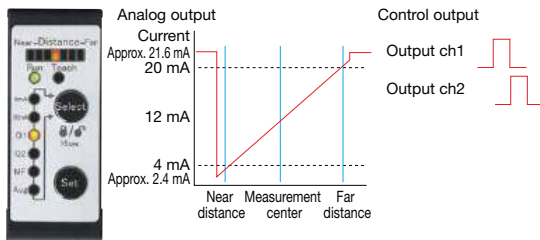


Low cost version that eliminates unnecessary circuits

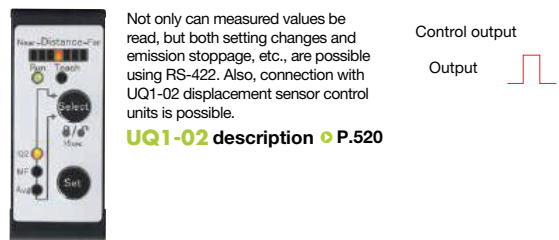
Realizing a high level of cost performance with a wide output-based lineup

While many of our competitors' displacement sensors have multiple types of measured value outputs, customers can make selections from "analog current + 2ch control output type", "analog voltage + 2ch control output type", "RS-422 + control output type", based on the input device used. Also, by eliminating unnecessary circuits, a highest-in-class level of cost performance has been realized. These laser displacement sensors are highly-accurate, low in cost, and easy to introduce.

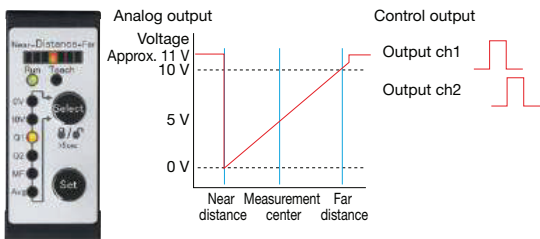
Analog current + 2ch control output type



RS-422 + control output type



Analog voltage + 2ch control output type



Specifications

Diffuse-reflective type Measurement distance based specifications

| Model | CD33-30□□□ | CD33-50□□□ | CD33-85□□□ | CD33-120□□□ | CD33-250□□□ |
|---|--|--|--|--|--|
| Center of measurement range | 30 mm | 50 mm | 85 mm | 120 mm | 250 mm |
| Measurement range | ±4 mm | ±10 mm | ±20 mm | ±60 mm | ±150 mm |
| F.S. (full scale) | 8 mm | 20 mm | 40 mm | 120 mm | 300 mm |
| Light source | Red semiconductor laser, wavelength: 655 nm, Maximum output: 1 mW | | | | |
| Laser class | IEC/JIS: CLASS 2 FDA: CLASS II | | | | |
| Spot size ¹ | 0.1 × 0.1 mm | 0.5 × 1.0 mm | 0.75 × 1.25 mm | 1.0 × 1.5 mm | 1.75 × 3.5 mm |
| Linearity | ±0.1% F.S. | | | | ±0.3% F.S. |
| Repeat accuracy | 2 μm (4 μm when response time is set to FAST) | 5 μm (8 μm when response time is set to FAST) | 10 μm (15 μm when response time is set to FAST) | 30 μm (45 μm when response time is set to FAST) | 75 μm (100 μm when response time is set to FAST) |
| Sampling period | 0.5 ms/1 ms/1.5 ms/2 ms | | | | 0.75 ms/1 ms/1.5 ms/2 ms |
| Response time ² Averaging | Fast | 5 ms or less: Averaging 1 time (1 ms) + sensitivity switching time (Max. 4 ms) | | | 7.5 ms or less: Averaging 1 time (1.5 ms) + sensitivity switching time (Max. 6 ms) |
| | Standard | 12.5 ms or less: Averaging 16 times (8.5 ms) + sensitivity switching time (Max. 4 ms) | | | 19 ms or less: Averaging 16 times (13 ms) + sensitivity switching time (Max. 6 ms) |
| | High-resolution | 36.5 ms or less: Averaging 64 times (32.5 ms) + sensitivity switching time (Max. 4 ms) | | | 55 ms or less: Averaging 64 times (49 ms) + sensitivity switching time (Max. 6 ms) |
| Temperature drift | ±0.08%/°C F.S. | | | | |
| Indicators | Distance indicator | LED bar display on operation surface (25-step) | | | |
| | Output indicator | Q1 and Q2 LED lights up during output (orange) | | | |
| | Input indicator | MF LED lights up during input (orange) | | | |
| MF (multi-function) input | Choose from laser OFF, teaching ³ , sample & hold Response time: 3 ms or less | | | | |
| Connection type | Cable type: Cable length: 2 m (ø5) Connector type: M12, 8-pin | | | | |
| Protection circuit | Reverse connection protection, overcurrent protection function | | | | |
| Degree of protection | IP67 | | | | |
| Ambient temperature/humidity | -10 to +45°C / 35 to 85% RH (no freezing or condensation) | | | | |
| Ambient illuminance | Sunlight: 10,000 lx Incandescent lamp: 3,000 lx | | | | |
| Vibration resistance | 10 to 55 Hz; double amplitude 1.5 mm; 2 hours in each of the X, Y, and Z directions | | | | |
| Shock resistance | Approx. 50 G (500 m/s ²), 3 times in each of the X, Y, and Z directions | | | | |
| Warm-up time | Approx. 15 minutes | | | | |
| Material | Housing: PBT, Front cover: PMMA, Cable: PVC | | | | |
| Weight without cable | Approx. 65 g | | | | |

Diffuse-reflective type Output based specifications

| Type | Analog current output type | Analog voltage output type | RS-422 type |
|--------------------------------|--|---|--------------------------|
| Model | NPN type | CD33-□□NA | CD33-□□N-422 |
| | PNP type | CD33-□□PA | CD33-□□P-422 |
| Supply voltage | 12 to 24 VDC, ±10/-5% | | 12 to 24 VDC, ±10/-5% |
| Current consumption | Max. 85 mA (including analog output) | | Max. 55 mA |
| Control output | Output channel No. | 2ch: Q1, Q2 (default setting of self-diagnosis output for Q2) | |
| | Output method | NPN/PNP open collector output, Max. 100 mA / 30 VDC, residual voltage 1.8 V | |
| Analog output/serial interface | 4 to 20 mA, load impedance: 300 Ω or less | 0 to 10 V, output impedance: 100 Ω | RS-422 9.6 k to 256 kbps |
| Applicable regulations | EMC directive (2004/108/EC) / FDA regulations (21 CFR 1040.10) | | |
| Applicable standards | EN 60947-5-7 | | EN 60947-5-2 |

<Measurement conditions> The measurement conditions are as follows unless otherwise designated: Ambient temperature of +23°C (normal temperature), Supply voltage 24 VDC, Response time: High-resolution, Center of measurement range, Measurement target: 50 × 50 mm white ceramic.

*1 Defined with center strength 1/e² (13.5%) at the center of measurement range. There may be leak light other than the specified spot size. The sensor may be affected when there is a highly reflective object in the range of the light axis.

*2 The response time is a time in which the sensitivity switching time has been added. The sensitivity switching time fluctuates within a max. range of 4 ms (6 ms for CD33-250N□) depending on measurement conditions. Also, if the sampling period is long, the response time will also increase proportionately.

Ex.: Sampling period 500 μs → 1000 μs: Response time 12.5 ms → Approx. 25 ms

*3 If external teaching is selected, setting items can be changed as shown in the table below depending on the input time thereof.

| Setting items | Input time | Setting items | Input time |
|--|---------------|---|-----------------|
| 1st point for span adjustment | 70 to 130 ms | 1-point teaching of control output Q2 | 470 to 530 ms |
| 2nd point for span adjustment | 170 to 230 ms | Please input the same time for the 2nd point of 2-point teaching within one minute. | |
| 1-point teaching of control output Q1 Please input the same time for the 2nd point of 2-point teaching within one minute. | 270 to 330 ms | Inverted 1-point teaching of control output Q2 | 570 to 630 ms |
| Inverted 1-point teaching of control output Q1 | 370 to 430 ms | Offset (zero reset) | 670 to 5000 ms |
| | | Clearing offset | 5000 ms or more |

C-MOS laser displacement sensor **CD33** series

Specifications

■ Specular reflection type

| Model | NPN type | CD33-L30□N-422 | CD33-L50□N-422 | CD33-L85□N-422 |
|------------------------------|--|--|----------------|----------------|
| | PNP type | CD33-L30□P-422 | CD33-L50□P-422 | CD33-L85□P-422 |
| Measurement target object | Specular object, glass | | | |
| Center of measurement range | 26.3 mm | 47.3 mm | 82.9 mm | |
| Measurement range | ±2 mm | ±5 mm | ±10 mm | |
| F.S. (full scale) | 4 mm | 10 mm | 20 mm | |
| Light source | Red semiconductor laser, wavelength: 655 nm, Maximum output: 390 μW | | | |
| Laser class | IEC/JIS: CLASS 1 FDA: CLASS II | | | |
| Spot size ¹ | 0.1 × 0.1 mm | | | |
| Linearity | ±0.2% F.S. | | | |
| Repeat accuracy | 1 μm | 2.5 μm | 5 μm | |
| Sampling period | 0.5 (default setting), 4-stage switching is possible between 1 ms, 1.5 ms, 2 ms | | | |
| Response time ² | Fast | 5 ms or less: Averaging 1 time (1 ms) + sensitivity switching time (Max. 4 ms) | | |
| | Standard | 12.5 ms or less: Averaging 16 times (8.5 ms) + sensitivity switching time (Max. 4 ms) | | |
| Averaging | High-resolution | 36.5 ms or less: Averaging 64 times (32.5 ms) + sensitivity switching time (Max. 4 ms) | | |
| | Control output | 1ch: Q2 (default setting of self-diagnosis output) | | |
| Output method | NPN/PNP open collector output, Max. 100 mA / 30 VDC, residual voltage 1.8 V | | | |
| Analog output | Not equipped | | | |
| Serial interface | RS-422 9.6 k to 256 kbps | | | |
| Temperature drift | ±0.08%/°C F.S. | | | |
| Indicators | Distance indicator | LED bar display on operation surface (25-step) | | |
| | Output indicator | Q2 LED lights up during output (orange) | | |
| | Input indicator | MF LED lights up during input (orange) | | |
| MF (multi-function) input | Choose from laser OFF, teaching ³ , sample & hold Response time: 3 ms or less | | | |
| Supply voltage | 12 to 24 VDC, ±10/-5% | | | |
| Current consumption | Max. 55 mA | | | |
| Connection type | Cable type: Cable length: 2 m (ø5) Connector type: M12, 8-pin | | | |
| Protection circuit | Reverse connection protection, overcurrent protection function | | | |
| Degree of protection | IP67 | | | |
| Ambient temperature/humidity | -10 to +45°C / 35 to 85% RH (no freezing or condensation) | | | |
| Ambient illuminance | Sunlight: 10,000 lx Incandescent lamp: 3,000 lx | | | |
| Vibration resistance | 10 to 55 Hz; double amplitude 1.5 mm; 2 hours in each of the X, Y, and Z directions | | | |
| Shock resistance | Approx. 50 G (500 m/s ²), 3 times in each of the X, Y, and Z directions | | | |
| Applicable regulations | EMC directive (2004/108/EC) / FDA regulations (21 CFR 1040.10) | | | |
| Applicable standards | EN 60947-5-2 | | | |
| Warm-up time | Approx. 15 minutes | | | |
| Material | Housing: PBT, Front cover: PMMA, Cable: PVC | | | |
| Weight without cable | Approx. 65 g | | | |

<Measurement conditions>

The measurement conditions are as follows unless otherwise designated: Ambient temperature of +23°C (normal temperature), Supply voltage 24 VDC, Response time: High-resolution, Center of measurement range, Measurement target: aluminum deposition mirror.

¹ Defined with center strength $1/e^2$ (13.5%) at the center of measurement range. There may be leak light other than the specified spot size. The sensor may be affected when there is a highly reflective object in the range of the light axis.

² The response time is a time in which the sensitivity switching time has been added. The sensitivity switching time fluctuates within a max. range of 4 ms depending on measurement conditions. Also, if the sampling period is long, the response time will also increase proportionately.

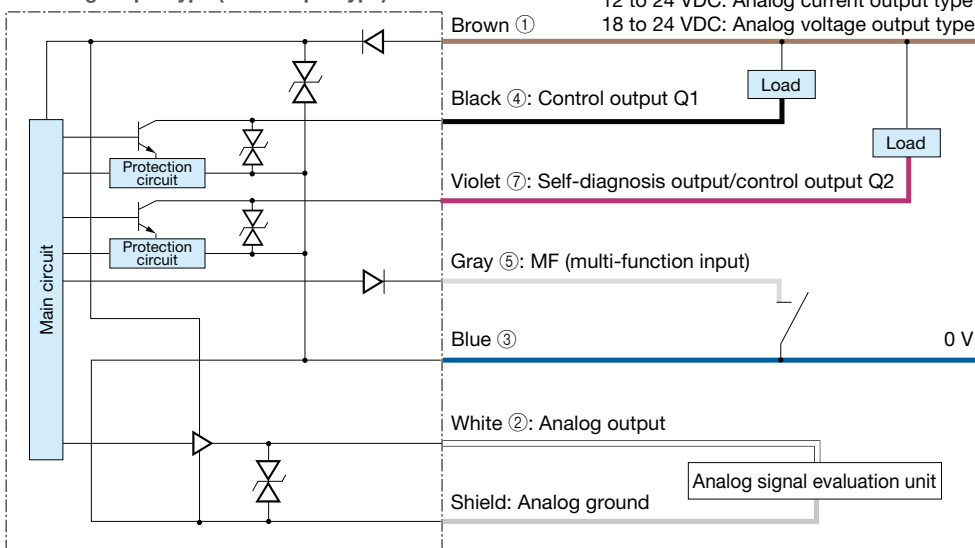
Ex.: Sampling period 500 μs → 1000 μs: Response time 12.5 ms → Approx. 25 ms

³ If external teaching is selected, setting items can be changed as shown in the table below depending on the input time thereof.

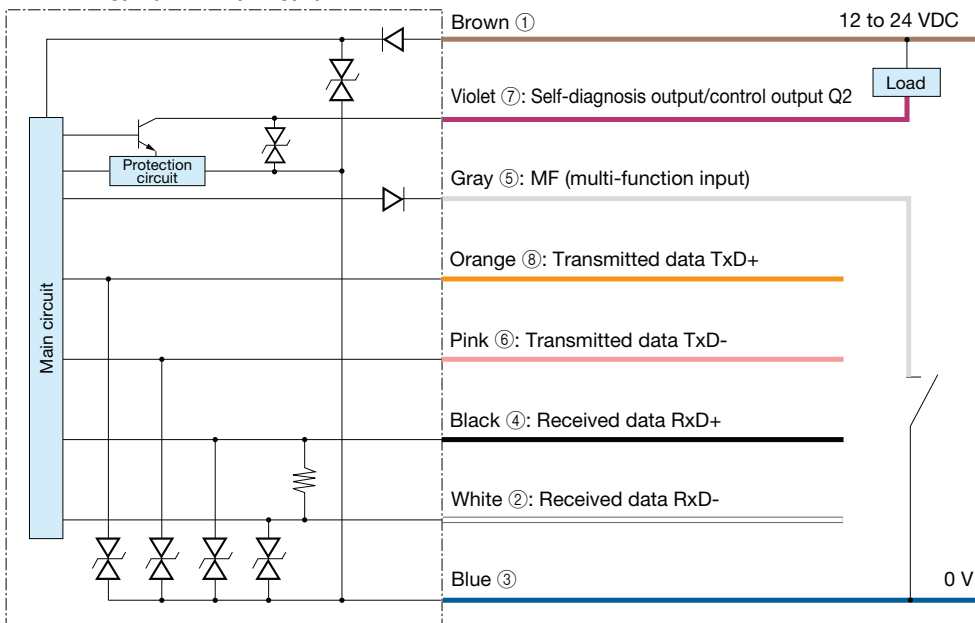
| Setting items | Input time |
|--|-----------------|
| 1-point teaching of control output Q2 Please input the same time for the 2nd point of 2-point teaching within one minute. | 470 to 530 ms |
| Inverted 1-point teaching of control output Q2 | 570 to 630 ms |
| Offset (zero reset) | 670 to 5000 ms |
| Clearing offset | 5000 ms or more |

I/O circuit diagram

Analog output type (NPN output type)

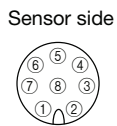


RS-422 type (NPN output type)



Connector type

(Pin configuration)



Connector cable side



- ① Supply voltage
- ② Analog output/Received data RxD-
- ③ 0 V
- ④ Control output Q1/Received data RxD+

- ⑤ Multi-function input
- ⑥ Transmitted data TxD-
- ⑦ Self-diagnosis output/control output Q2
- ⑧ Transmitted data TxD+

Connecting

- ① to ⑧ are connector pin No.
- Because the connector type is not equipped with an analog ground wire, please use by connecting the analog ground terminal of the analog input device and 0 V of the sensor power supply.

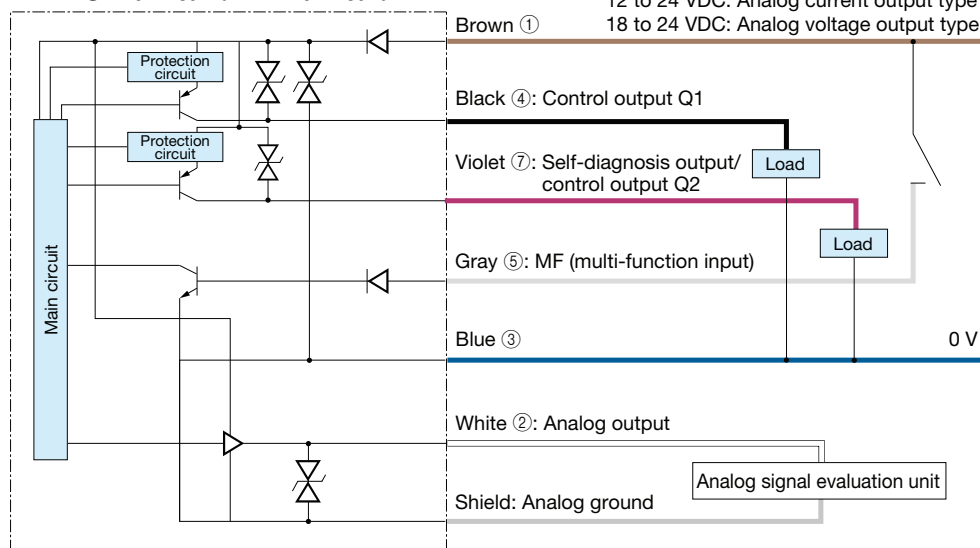
Notes

- When using a switching regulator for the power supply, be sure to ground the frame ground terminal.
- Avoid wiring in parallel with or in the same piping as high-voltage wires or power lines. Doing so may lead to malfunctions caused by noise. Also, shorten the power supply and signal wires as much as possible.
- Avoid using the transient state while the power is on (approx. 1.5 s).

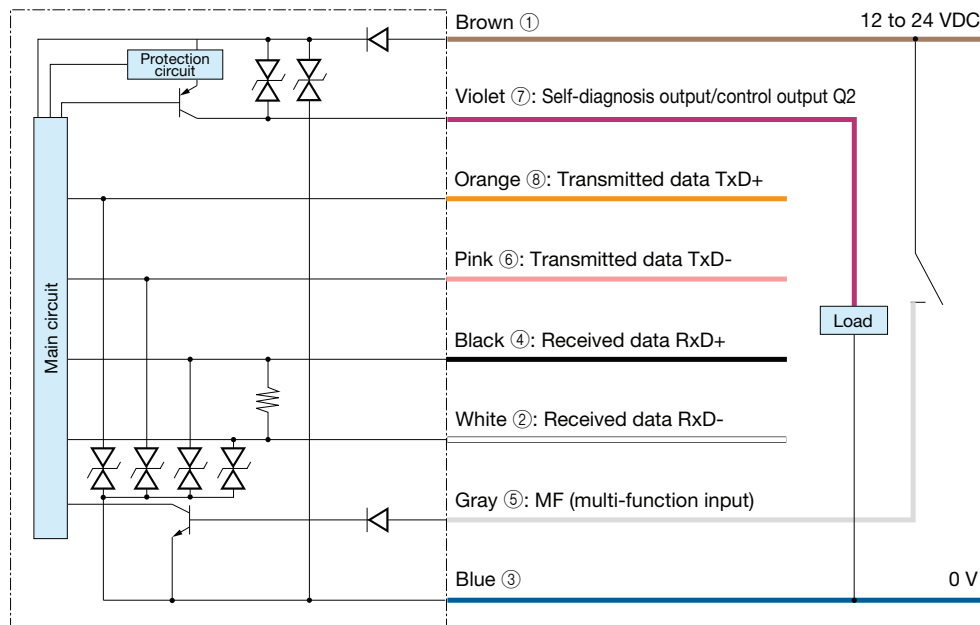
C-MOS laser displacement sensor **CD33** series

I/O circuit diagram

■ Analog output type (PNP output type)



■ RS-422 type (PNP output type)



■ Connector type

(Pin configuration)

Sensor side



- ① Supply voltage
- ② Analog output/Received data RxD-
- ③ 0 V
- ④ Control output Q1/Received data RxD+

Connector cable side



- ⑤ Multi-function input
- ⑥ Transmitted data TxD-
- ⑦ Self-diagnosis output/control output Q2
- ⑧ Transmitted data TxD+

Connecting

- ① to ⑧ are connector pin No.
- Because the connector type is not equipped with an analog ground wire, please use by connecting the analog ground terminal of the analog input device and 0 V of the sensor power supply.

Notes

- When using a switching regulator for the power supply, be sure to ground the frame ground terminal.
- Avoid wiring in parallel with or in the same piping as high-voltage wires or power lines. Doing so may lead to malfunctions caused by noise. Also, shorten the power supply and signal wires as much as possible.
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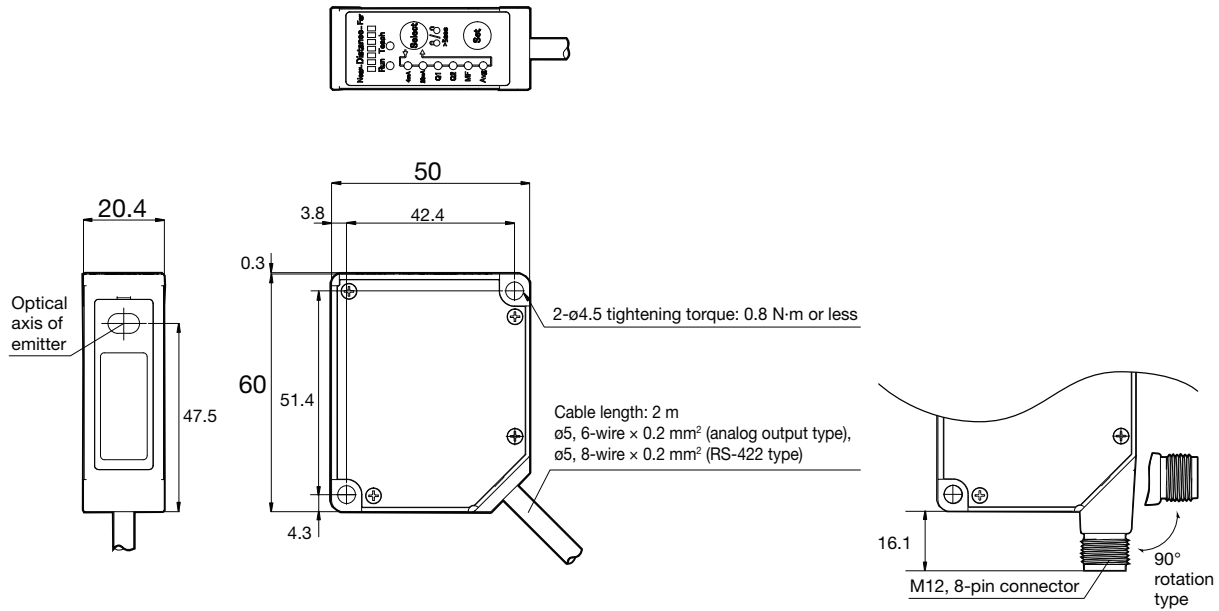
Dimensions

Sensor

■ Cable type

■ Connector type

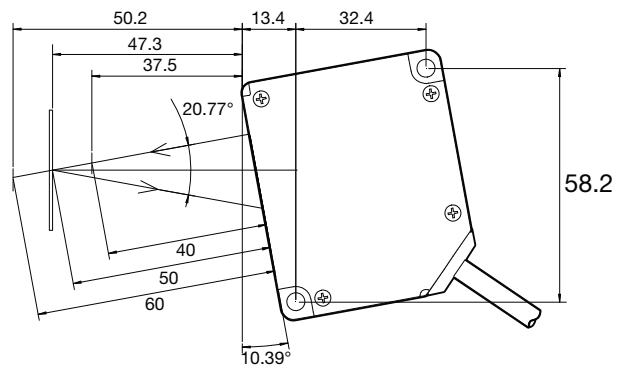
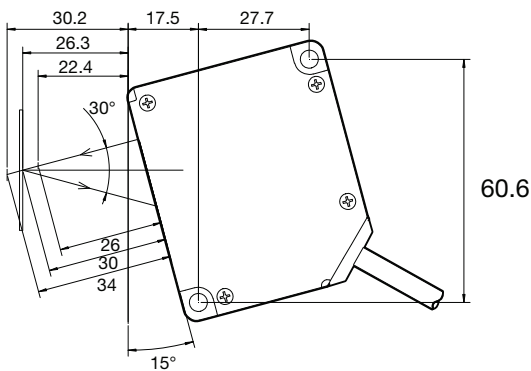
(Unit: mm)



Specular reflection type (side view)

CD33-L30□-422

CD33-L50□-422



Photoelectric Sensors

Specialized Photoelectric Sensors

Laser Displacement Sensors

C-MOS Built-in Amplifiers

CDX

CDA

LS

CD22

CD33

CD4

CD5

UQ1-01

UQ1-02



480

Laser Displacement Sensors

Photoelectric Sensors

Specialized Photoelectric Sensors

Laser Displacement Sensors

C-MOS Built-in Amplifiers

CDX

CDA

LS

CD22

CD33

CD4

CD5

UQ1-01

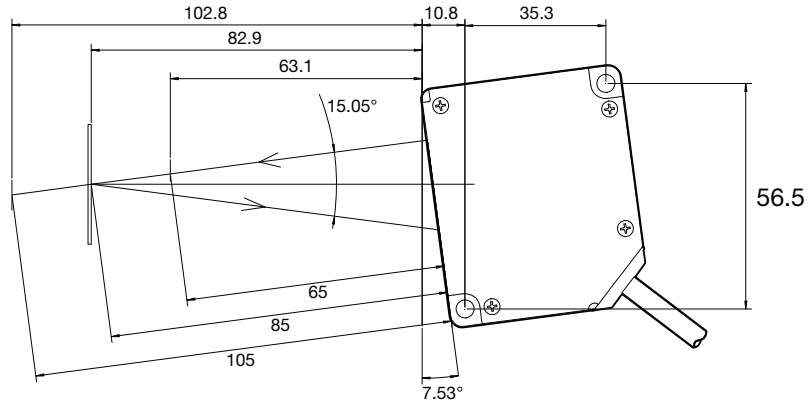
UQ1-02

C-MOS laser displacement sensor CD33 series

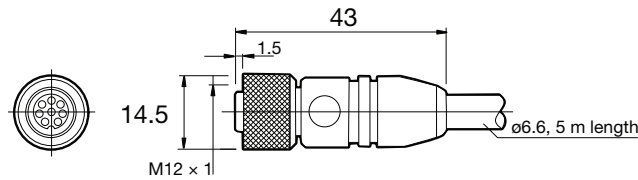
Dimensions

CD33-L85□-422

(Unit: mm)



Connector cable DOL-1208-G05MF



Cable material: PVC
Conductor cross-section: 0.25 mm²



Photoelectric Sensors

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Laser Displacement Sensors

C-MOS Built-in Amplifiers

CDX

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CD22

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UQ1-01

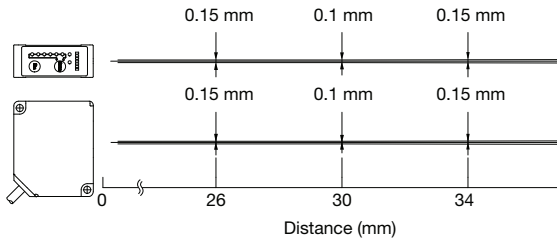
UQ1-02

Typical characteristic data

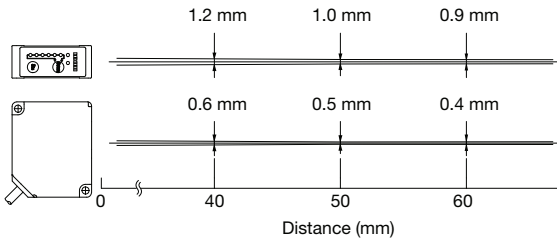
Spot size

Diffuse-reflective type

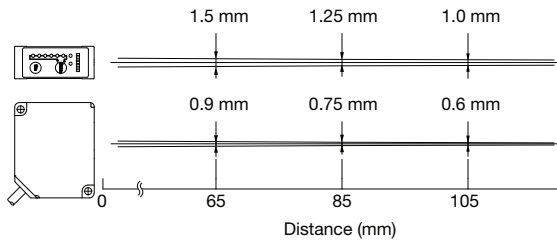
CD33-30



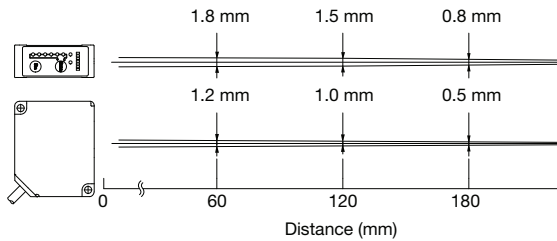
CD33-50



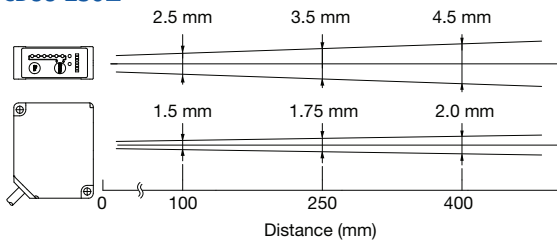
CD33-85



CD33-120

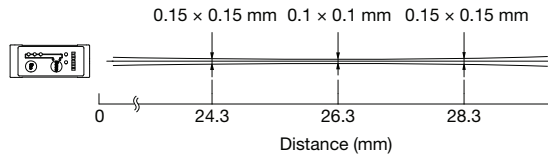


CD33-250

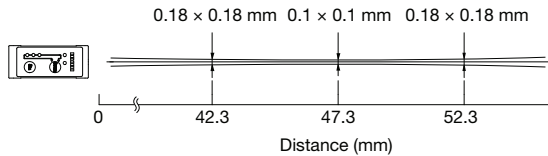


Specular reflection type

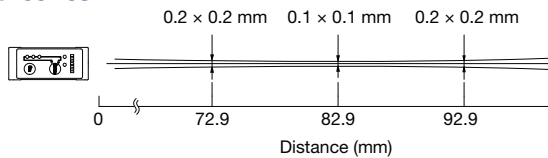
CD33-L30-422



CD33-L50-422



CD33-L85-422



C-MOS laser displacement sensor CD33 series

Installation of sensor

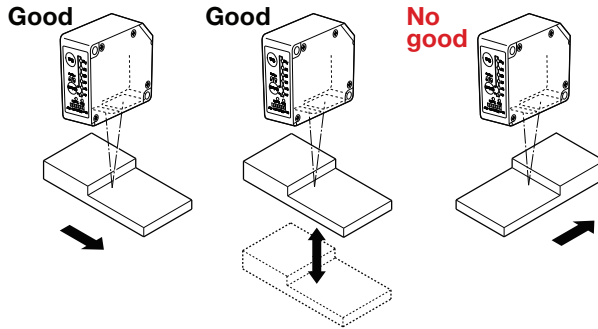


Warning

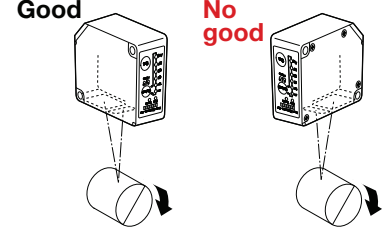
- Install the sensor at a height that is not at worker eye level.
- Make sure to turn the power off before connecting or removing sensors.

Mount the sensor head so that the detection surface (optical plane) is always parallel to the detection target. Adjust the target so that the spot aligns with the detection position, and ensure that the bar graph distance indicator lights up orange at the reference detection surface (center of change).

● Workpieces with large fluctuations in height difference or color

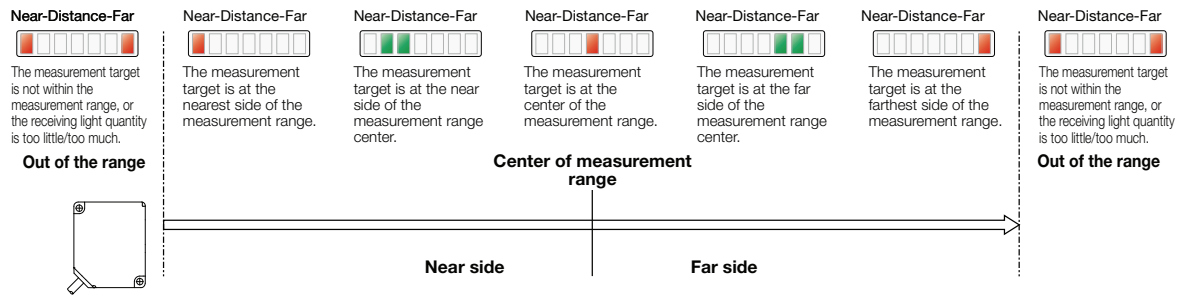


● Rotating workpieces



Bar graph distance indicator

By combining individual lighting/multiple lighting and lighting/flashing patterns, distances will be displayed in 25 steps (the following example shows 5 steps).



Warning

Do not look directly at the laser or intentionally aim the laser beam in another person's eyes. Doing so may cause damage to the eyes or health.

Photoelectric Sensors

Specialized Photoelectric Sensors

Laser Displacement Sensors

C-MOS Built-in Amplifiers

CDX

CDA

LS

CD22

CD33

CD4

CD5

UQ1-01

UQ1-02



Precautions for laser use

This product emits a Class 1/Class 2 (II) visible laser beam that is compliant with JIS C 6802/IEC/FDA laser safety standards. Because English language warnings indicating the sensor as Class 1 or Class 2 (II), as well as explanation labels, are located on the side of the sensor, please replace these warnings/explanation labels with the Japanese language warnings/explanation labels included in the box when using in Japan.

Type of laser used in this product

| | |
|------------|-------------------------|
| Type | Red semiconductor laser |
| Wavelength | 655 nm |
| Output | 390 μW/1 mW |



If you install this product in a piece of machinery that will then be exported to the United States, it is necessary to follow laser standards as stipulated by the American Food and Drug Administration (FDA). This product has already been submitted to the CDRH (Center for Devices and Radiological Health). (Please inquire for details.)

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